

ECE ECE145A (undergrad) and ECE218A (graduate)

Mid-Term Exam. October 26, 2015

Do not open exam until instructed to.

Open notes, open books, etc

You have 1 hr and 15 minutes.

Use any and all reasonable approximations (5% accuracy is fine.), **AFTER STATING THEM.**

Problem	Points Received	Points Possible
1	15	
2a	10	
2b	15	
3a	10	
3b	10	
3c	10	
4	15	
5	15	
total	100	

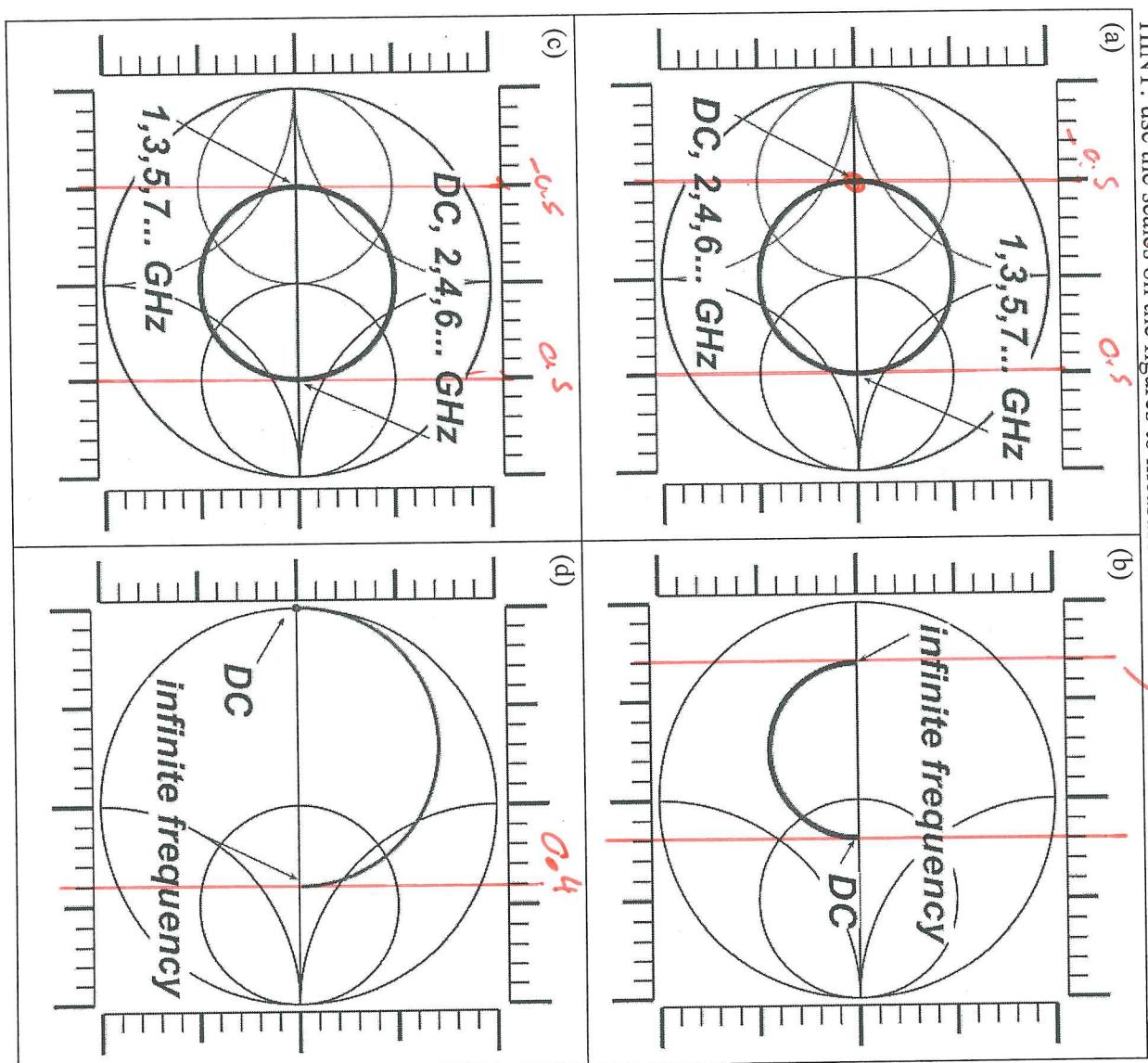
Name: Solution.

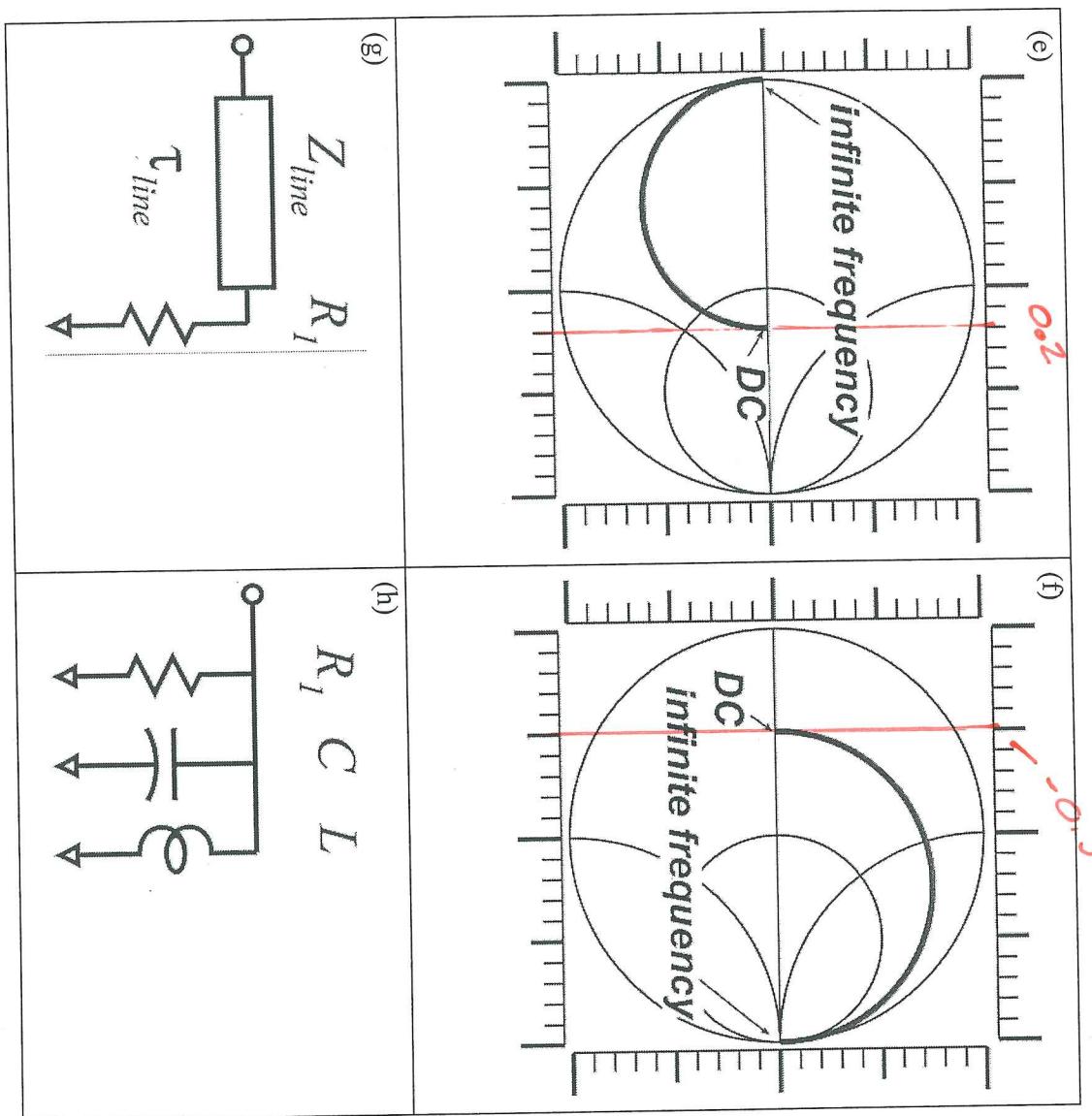
Problem 1, 15 points
The Smith Chart and Frequency-Dependent Impedances.

HINT: use the scales on the figures to measure distances as needed.

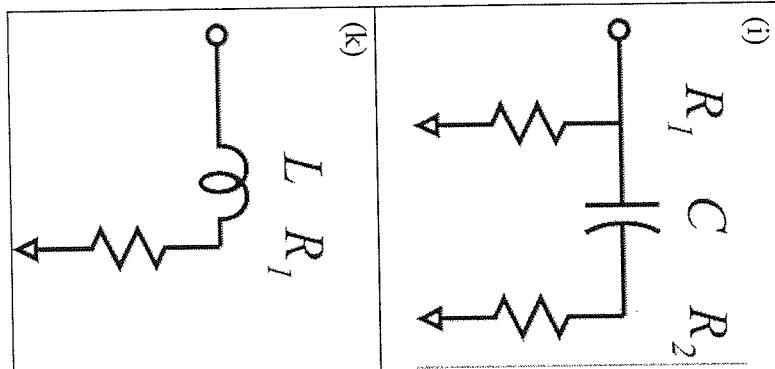
~~0.1~~

~~0.2~~

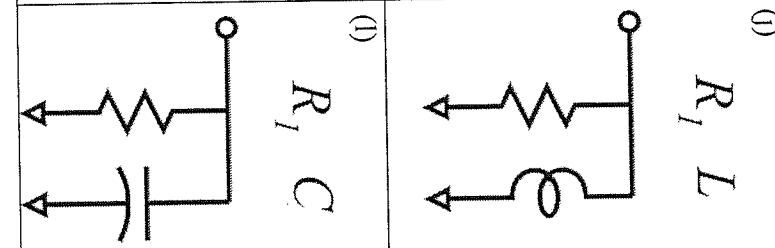




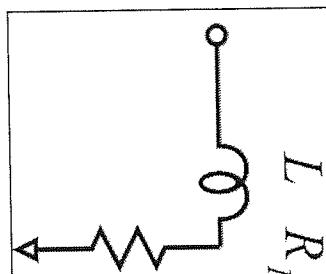
(i)



(j)



(k)



First match each Smith Chart with each circuit. Then determine as many component values as is possible (RLC values, transmission line delays and characteristic impedances)...note that some values cannot be determined with the information given. The charts all use 50 Ohm normalization:

Smith chart (a). Circuit= $\frac{Z_1 + jZ_0}{Z_1 - jZ_0}$. Component values= $Z_{1,10} = 50\Omega$, $R_2 = 17\Omega$, $T_1 = 25\text{ops}$
 Smith chart (b). Circuit= j . Component values= $R_1 = 75\Omega$, $R_2 = 10\Omega$, $T_1 = 2\text{rops}$
 Smith chart (c). Circuit= j . Component values= $Z_{1,10} = 50\Omega$, $R_1 = 15\Omega$, $T_1 = 2\text{rops}$
 Smith chart (d). Circuit= j . Component values= $R_1 = 13.3\Omega$, $R_2 = 17\Omega$
 Smith chart (e). Circuit= (R) . Component values= $R_1 = 75\Omega$
 Smith chart (f). Circuit= (R) . Component values= $R_1 = 16.7\Omega$

1) $I_s = 50\Omega$ trans. ss. on line load. $\rightarrow Z_L = 50/3 = 16.7\Omega$ (1)

$$w/ \frac{Z_L}{Z_0} = \frac{1+D_{dc}}{1-D_{dc}} = \frac{1-0.5}{1+0.5} = 1/3$$

3

4) ω : the line is $1/2$ long $\rightarrow 2\pi/26\Omega = 1\text{ long } \rightarrow 26\text{ rad/s}$ (1)

4.

4.

3

5) $D = 0.2 @ DC$
 $Z/Z_0 = \frac{1.2}{0.8} = 1.5 \rightarrow Z = 1.5 \cdot 50\Omega = 75\Omega = R_1$ (1)

$$\omega = -0.7 @ f \rightarrow \infty$$

$$Z/Z_0 = \frac{1-0.7}{1+0.7} = \frac{0.3}{1.7} = 0.176 \rightarrow Z = 8.8\Omega = R_1//R_2$$

$$\frac{a}{R} = \frac{1}{R_2} \quad \frac{1}{R_2} = \frac{1}{8.8} - \frac{1}{17.6} = \frac{1}{1.7}$$

5.

$$R_2 = 9.9\Omega$$

c) Similar to (a)

Circuit is GP

$$R = \frac{Z_0}{\alpha} = \frac{1+0.5}{1-0.5} = 3 Z_0 = 150 \Omega$$

but $R_L = ?$

$$I_{Dc} = 0.5 \rightarrow R_L = Z_0 \frac{1+0.5}{1-0.5} = 3 Z_0 = 150 \Omega$$

$$Z_0 = 50 \Omega, \quad \alpha = 25 \text{ ps} \cdot \Omega$$

3

d) This is network (j)

$$R = Z_0 \frac{1+0.4}{1-0.4} = 50 \Omega \frac{1.4}{0.6} = 120 \Omega$$

g.

Network (G)

$$R = Z_0 \frac{1+0.2}{1-0.2} = 50 \Omega \frac{1.2}{0.8} = 75 \Omega$$

2

2

(F) Network (F)

$$R = Z_0 \frac{1-0.5}{1+0.5} = 50 \Omega \frac{0.5}{1.5} = 50 \Omega = 16.7 \Omega$$

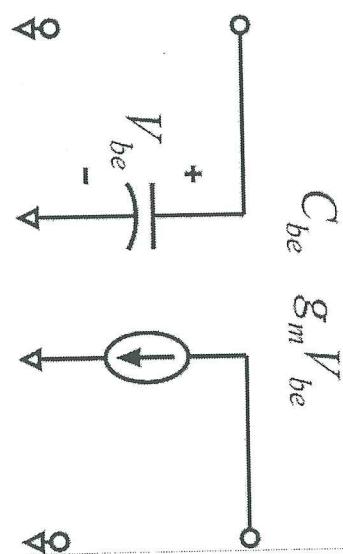
1

Problem 2, 25 points
2-port parameters and Transistor models

Part a, 10 points

For the network at the right, give algebraic expressions for the four S-parameters.

Assume a normalization to impedance Z_0 for the S parameters.



$$\frac{Z_{in}}{Z_0} = \frac{1}{j\omega C_{be} Z_0}$$

$$3 \Rightarrow S_{11} = \frac{\frac{1}{j\omega C_{be} Z_0} - 1}{j\omega C_{be} Z_0 + 1}$$

$$2 \left[\frac{Z_{out}}{Z_0} = \infty \right]$$

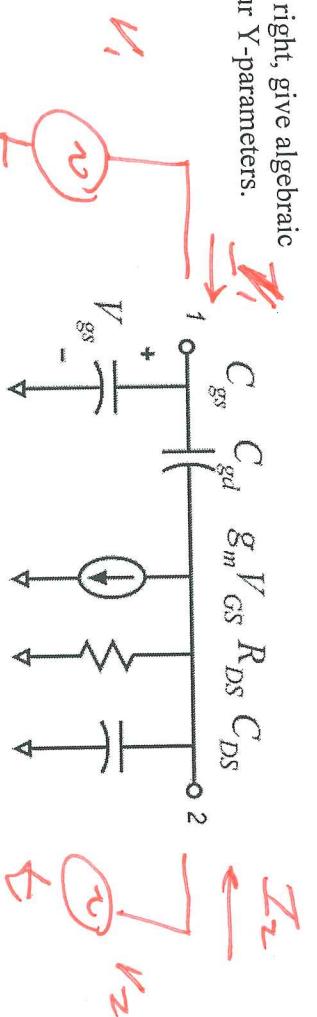
$$\Rightarrow S_{22} = 1.0$$

$$2 \left[\begin{array}{l} \text{Inspection, } S_{12} = 0 \\ S_{21} = 2 \frac{V_o / V_{be}}{Y_{in} + Y_{out} + Z_0} = Z_0 \end{array} \right]$$

$$= 2 \cdot \frac{\frac{1}{j\omega C_{be}}}{j\omega C_{be} + Z_0}$$

$$3 \left[\begin{array}{l} S_{21} = -2g_m Z_0 \\ 1 + j\omega C_{be} Z_0 \end{array} \right]$$

Part b, 15 points
 For the network at the right, give algebraic
 expressions for the four Y-parameters.



$$\left[\begin{array}{c} I_1 \\ I_2 \end{array} \right] = \left[\begin{array}{cc} -\gamma_1 & \gamma_{12} \\ \gamma_1 & \gamma_{22} \end{array} \right] \left[\begin{array}{c} v_1 \\ v_2 \end{array} \right]$$

by inspection:

$$1 \quad \gamma_1 = -j\omega(G_{GS} + G_{GD})$$

$$3 \quad \gamma_{12} = -j\omega G_D.$$

$$4 \quad \gamma_{22} = g_m - j\omega G_D.$$

$$4 \quad \left[\begin{array}{l} \gamma_{22} = 1/R_{DS} + j\omega G_D \\ \text{or } G_{DS} \end{array} \right]$$

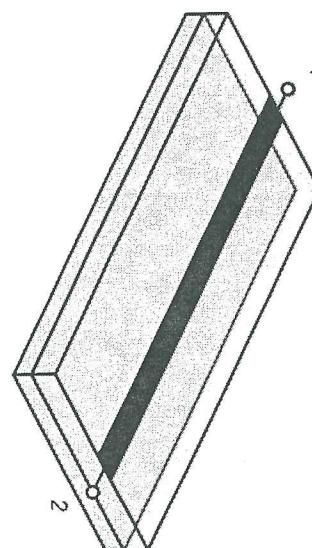
Problem 3, 30 points
Transmission-line theory

Hint: we are testing here your understanding of transmission-lines and their relationships to lumped elements. If the calculation appears to be extremely difficult, you may possibly be missing some key insight.

Part a, 7.5 points

You have a microstrip line of 10 cm length, and 5mm width. The substrate is 2mm thick and has a dielectric constant of 2.0.

Treat fringing fields approximately by assuming that the effective conductor width is the physical conductor width plus twice the substrate thickness



Find the characteristic impedance of the line, the velocity, the total line inductance, and the total line capacitance.

$$Z_0 = 2 \pi r_f \cdot w = 5 \text{ mm}, \quad w_{eff} = 9 \text{ mm.}$$

What follows is very approximate:

$$Z_0 \approx \frac{37\pi}{\sqrt{\epsilon_r}} \cdot \frac{H}{w_{eff}} = \frac{37\pi}{\sqrt{2}} \frac{2 \text{ mm}}{9 \text{ mm}} \approx 60 \Omega.$$

$$v \approx \frac{c}{\sqrt{\epsilon_r}} = 2.12 \cdot 10^8 \text{ m/s.}$$

$$l = \frac{10 \text{ cm}}{v} = 4.7 \cdot 10^{-9} \text{ seconds.} = 0.47 \text{ ns}$$

$$\gamma = \text{line delay} = \frac{1}{v}$$

$$L = \gamma Z_0 = 0.47 \text{ ns} \cdot 60 \Omega = 28.2 \text{ nH.}$$

$$C = \frac{\gamma}{Z_0} = \frac{0.47 \text{ ns}}{60 \Omega} = \underline{\underline{7.8 pF}}$$

$$C = \frac{\epsilon_0 \cdot A}{d} = \frac{\epsilon_0 \cdot w_{eff} \cdot l}{d} = \frac{\epsilon_0 \cdot 9 \text{ mm} \cdot 10 \text{ cm}}{0.2 \text{ mm}} = \underline{\underline{1.62 \text{ pF}}}$$

Part b. 7.5 points

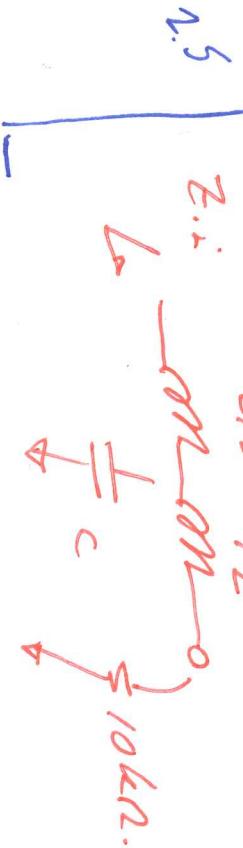
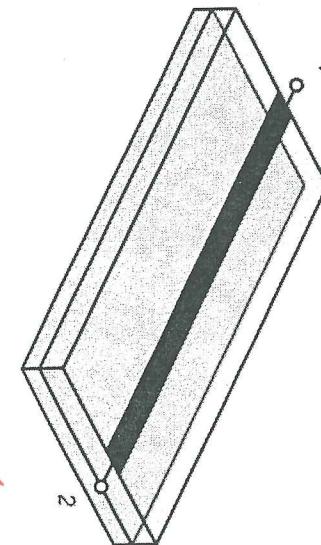
We now load port 2 with a resistance of 10 kOhm. Give an *approximate* expression for the frequency-dependent input impedance, measured at port 1. The approximation need be valid only over a DC-100MHz signal frequency range.

$$100\text{MHz} \cdot c_{\text{air}} = \frac{c_0 \mu_0}{\text{length}}$$

\Rightarrow use T or π .

$$L = 28\text{nH}$$

$$C = 7.8\text{pF}$$



2.5 now $R_L = 10\text{k}\Omega \gg \text{resonance}$.

2.5 so $L/R_L \ll R_{\text{LC}}$

\Rightarrow effect of inductance is negligible.

$$\Rightarrow Z_{\text{i}} = \frac{1}{j\omega C} \parallel 10\text{k}\Omega$$

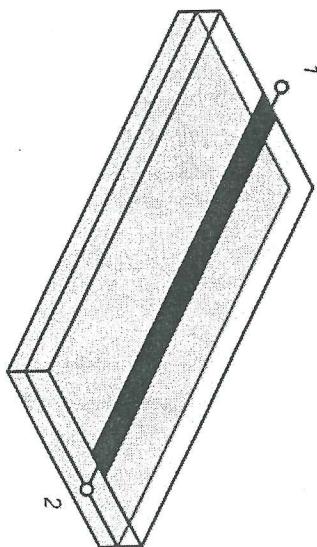
2.5

$$Z_{\text{i}} = j\frac{1}{\omega C} \parallel 10\text{k}\Omega = \frac{10\text{k}\Omega}{1 + j\omega C(10\text{k}\Omega)}$$

$$Z_{\text{i}} = \frac{10\text{k}\Omega}{1 + j\omega(7.8\text{pF})10\text{k}\Omega} = \frac{10\text{k}\Omega}{1 + j\omega(780\text{nS})}$$

Part c, 7.5 points

We now load port 2 with a resistance of 2 Ohms. Give an *approximate* expression for the frequency-dependent input impedance, measured at port 1. The approximation need be valid only over a DC-100MHz signal frequency range.



2.5
 $\omega T \ll 1$
 $\Rightarrow \text{length} \ll 1$

so use $\pi \alpha T$ approx. metrix.

$$\frac{1}{z} = \frac{1}{2} \sqrt{\frac{c}{\pi}} \frac{1}{T} \approx \frac{1}{2\pi R}$$

$$C = 2 \epsilon \eta / L$$

$$L = 7.4 \mu m$$

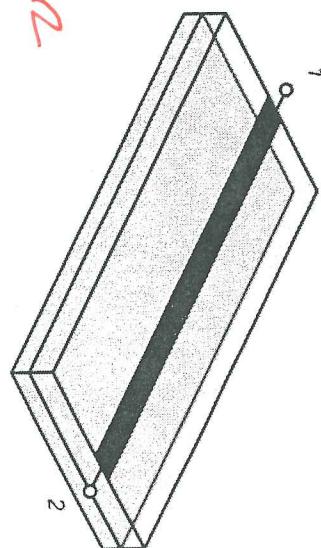
new $R_c \ll Z_0$, so $R_c \ll 1/R \Rightarrow$ ignore C .

$$Z_{in} = Z_0 + j \omega C Z_0 \pi t$$

$$Z_{in} = Z_0 + j \omega C Z_0 \pi t$$

Part d, 7.5 points

At what frequency is the line one quarter-wavelength in length? If we load port 2 with a 30 Ohm resistance, what would be the input impedance at port 1 at this frequency?



$$Z_0 = 60\Omega$$

$$\gamma = 0.47 \text{ ns} \approx 0.5 \text{ ns}.$$

3.5
quarter-wavelength when
 $\gamma = 1/4\pi = 1/2\pi s = 50 \text{ cm/Hz}$,

4
 $Z_i = \frac{Z_0}{1 - e^{-\gamma L}}$
 $L = \lambda/4 \Rightarrow 30\Omega$

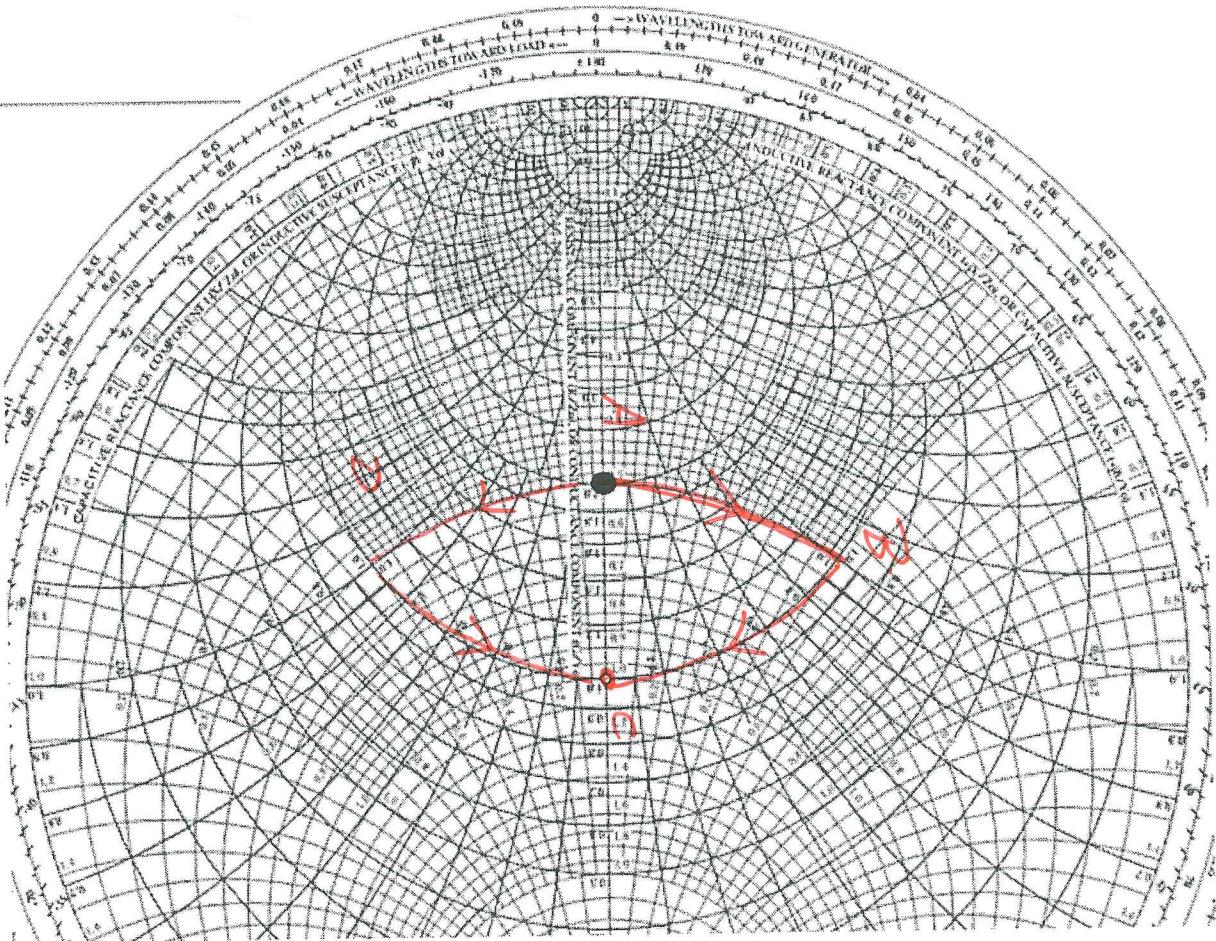
$$Z_i = Z_0 / 60\Omega = 1/2$$

at $\lambda/4 = L$, ~~$Z_i = Z_0$~~ $Z_i/Z_0 = Z_c/Z_0 = 2$

$$Z_i = 2 \cdot 60\Omega = 120\Omega$$

Problem 4, 15 points
Impedance-matching exercise.

The (50 Ohm normalization) Smith chart gives the input impedance of a circuit at 1 GHz signal frequency. Design a lumped-element matching network which converts this impedance to **500 Ohms** at 1 GHz. Give all element values.



Solutions are
A - B - C
and
A - D - C .

on cm $4\pi H$ 16π
 L $\frac{1}{6}$ $\frac{100}{3.2\mu F}$ $\frac{25}{100}$
 rad

Path ABC

Point A: $\mathcal{Y} = 0.5 + j0$; $\mathcal{Y} = 2 + j0$ [3]

Point B: ~~$\mathcal{Y} = \mathcal{Y}$~~ $= 0.5 + j0.5$.

$$\Delta \mathcal{Y} = j0.5 \Rightarrow \Delta Z = j0.5 \cdot 80 = j25\Omega = j\omega L$$

$$\omega L = 25\Omega \Rightarrow L = \frac{25\Omega}{2\pi(1\text{MHz})} = 4.01\text{H}$$

Point B: $\mathcal{Y} = 1 - j0$.] 4

Point C: $\mathcal{Y} = 1 + j0$.

$$\Delta \mathcal{Y} = +j1.0 \Rightarrow \Delta Y = \frac{j1.0}{50\Omega} = j0.02$$

$$\Rightarrow C = \frac{1}{50\Omega \cdot 2\pi f} = 3.2\mu F$$

Solution 1:
 --- Path ADC ---

or Solution 2:

Point A: $\mathcal{Y} = 2 + j0$; $\mathcal{Y} = 0.5 + j0$ [4]

Point D: $\mathcal{Y} = 0.5 - j0.5$

$$\Delta \mathcal{Y} = -j0.5 \Rightarrow \Delta Z = j25\Omega = 1/j\omega C$$

$$C = \frac{1}{25\Omega \cdot 2\pi f} = 6.4\mu F.$$

Point D: $\mathcal{Y} = 1 + j0$] 3

Point C: $\mathcal{Y} = 1 + j0$

$$\Rightarrow \Delta \mathcal{Y} = -j1.0 \Rightarrow \Delta Y = -\frac{j1.0}{50\Omega} = \frac{1}{50\Omega} = j0.02$$

$$6.4\mu F \quad C = \frac{50\Omega}{2\pi f} = 8.01\mu F$$

so

$$L = \frac{\phi}{\theta} = \frac{25\Omega}{15\%}$$

$$8.01\mu H$$

Problem 5, 15 points
Transmission-line parasitics.

Part a, 7.5 points

You have a microstrip line of 10 cm length, and 5mm width. The substrate is 2mm thick and has a dielectric constant of 2.0.

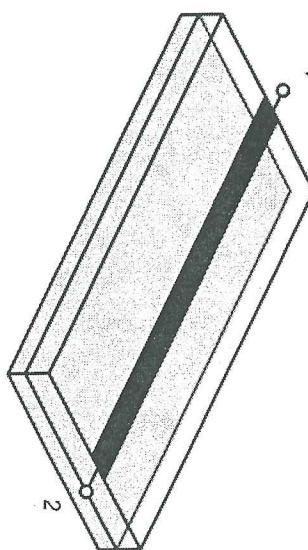
Neglect the fringing fields.

The conductivity of gold is

44.2×10^6 Siemens/meter and

- $\mu_0 = 4\pi \times 10^{-7} H/m$. Find (i) the skin depth, (ii) the attenuation constant α , and (iii) the total line attenuation at 10GHz signal frequency.

Hint---the skin depth is $\delta = \sqrt{2/\omega\mu_0\sigma}$



$$1 \quad \left[\begin{array}{l} \text{If we neglect fringing fields, then} \\ \frac{\delta}{w} = \frac{3770}{\sqrt{\epsilon_r}} \frac{w}{\lambda} = \frac{3770}{\sqrt{2.0}} \frac{5\text{mm}}{0.028} = 106.6\Omega. \\ \text{(high, because we have neglected fr. f.)} \end{array} \right]$$

$$1 \quad \left[\begin{array}{l} \delta = \sqrt{\frac{2}{\omega\mu_0\sigma}} = 0.7\mu\text{m} \\ \text{series res.istance per unit length:} \end{array} \right]$$

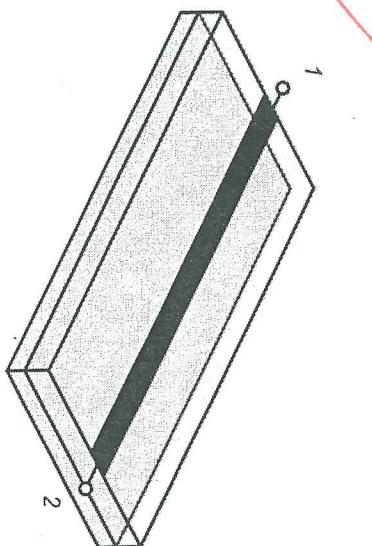
$$1 \quad r_s = 1/\sigma w = 6\text{ ohms/meter.} \quad 0.028$$

$$1.5 \quad \left[\begin{array}{l} \alpha = \text{loss coefficient} = r_s/2z = \text{ang. meters}^{-1}. \\ \text{Voltage attenuation} = \exp[-\alpha L] = \exp[-0.028 \text{ ang. meters}^{-1} \cdot 0.1 \text{ meter}] = 0.9972 \\ = \exp[-0.0028] \end{array} \right]$$

$$1.5 \quad \left[\begin{array}{l} \text{Attenuation, dB} = -20 \log_{10} [0.9972] = -0.024 \text{ dB} \\ \text{very small.} \end{array} \right]$$

Part b, 7.5 points

We are not happy with the line attenuation we calculated above. So, we choose to make the circuit board thicker, while adjusting the conductor width to keep the same characteristic impedance. (i) If we increase the board thickness by 5:1, what is the total line attenuation now? (ii) At what frequency might we expect to see lateral modes on the transmission-line?



Board 5:1 thicker
 \Rightarrow increased S.I., & decreased S.P.I.

$$\Rightarrow 5 \cdot 10^{-3} \text{ dB attenuation}$$

Board is 5:1 thicker, so far conductor is 25mm width.
 So far conductor is 25mm width.
 Line is 5:1 wider, i.e. 25mm width.

transverse modes when $\lambda/2 = 25\text{mm}$

2.5.

$$\Rightarrow \lambda_d = 50\text{mm} = 5\text{cm},$$

$$\lambda_0 = \lambda_d \sqrt{\epsilon_r} = 5\text{cm} \cdot \sqrt{2} \approx 7.1\text{cm}.$$

$$f_{10} = c \Rightarrow f_0 = c/\lambda_0 = \frac{3 \cdot 10^8 \text{ m/s}}{7.1 \text{ cm}}$$

$$= 4.2 \text{ GHz}$$

So, widening of the line was

in fact idea.